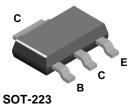




BCP54



NPN General Purpose Amplifier

This device is designed for general purpose medium power amplifiers and switching circuits requiring collector currents to 1.2 A. Sourced from Process 38.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	45	V
V _{CBO}	Collector-Base Voltage	45	V
V _{EBO}	Emitter-Base Voltage	5.0	V
Ic	Collector Current - Continuous	1.5	А
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES: 1) These ratings are based on a maximum junction temperature of 150 degrees C. 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

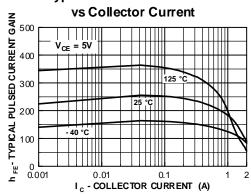
Thermal Characteristics TA = 25°C unless otherwise noted

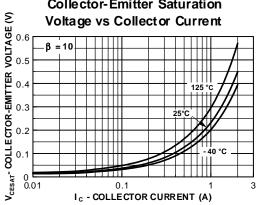
Symbol	Characteristic	Max	Units
		BCP54	
P _D	Total Device Dissipation	1.5	W
	Derate above 25°C	12	mW/∘C
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient	83.3	°C/W

NPN General Purpose Amplifier (continued)

d)

Symbol	Parameter	Test Conditions	Min	Max	Units
	RACTERISTICS		45		
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0$	45		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 100 \ \mu {\rm A}, \ I_{\rm E} = 0$	45		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{\rm E} = 10 \ \mu {\rm A}, \ I_{\rm C} = 0$	5.0		V
I _{CBO}	Collector-Cutoff Current	$V_{CB} = 30 \text{ V}, I_E = 0$		100	nA
		$V_{CB} = 30 \text{ V}, \text{ I}_{E} = 0, \text{ T}_{A} = 125^{\circ}\text{C}$		10	μΑ
I _{EBO} ON CHAR	Emitter-Cutoff Current	$V_{EB} = 5.0 \text{ V}, I_{C} = 0$		10	μA
ON CHAR		I _c = 5.0 mA, V _{ce} = 2.0 V	25		μΑ
ON CHAR	ACTERISTICS	I _C = 5.0 mA, V _{CE} = 2.0 V I _C = 150 mA, V _{CE} = 2.0 V	40	10 250	μΑ
ON CHAR	ACTERISTICS DC Current Gain	$I_{C} = 5.0 \text{ mA}, V_{CE} = 2.0 \text{ V}$ $I_{C} = 150 \text{ mA}, V_{CE} = 2.0 \text{ V}$ $I_{C} = 500 \text{ mA}, V_{CE} = 2.0 \text{ V}$	-		μA
ON CHAR h _{FE} V _{CE(sat)}	ACTERISTICS	$I_{C} = 5.0 \text{ mA}, V_{CE} = 2.0 \text{ V}$ $I_{C} = 150 \text{ mA}, V_{CE} = 2.0 \text{ V}$	40	250	
ON CHAR h_{FE} $V_{CE(sat)}$ $V_{BE(on)}$	ACTERISTICS DC Current Gain Collector-Emitter Saturation Voltage	$I_{C} = 5.0 \text{ mA}, V_{CE} = 2.0 \text{ V}$ $I_{C} = 150 \text{ mA}, V_{CE} = 2.0 \text{ V}$ $I_{C} = 500 \text{ mA}, V_{CE} = 2.0 \text{ V}$ $I_{C} = 500 \text{ mA}, I_{B} = 50 \text{ mA}$	40	250 0.5	V

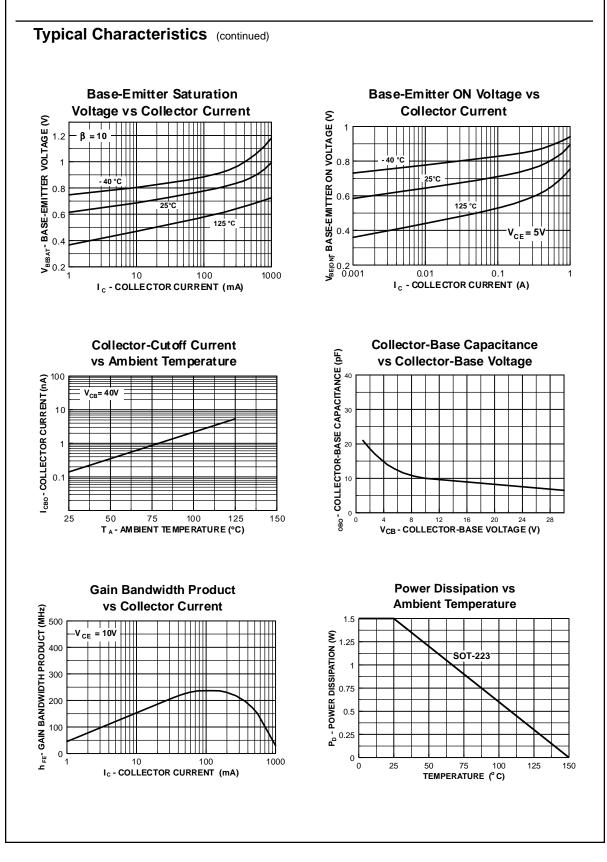


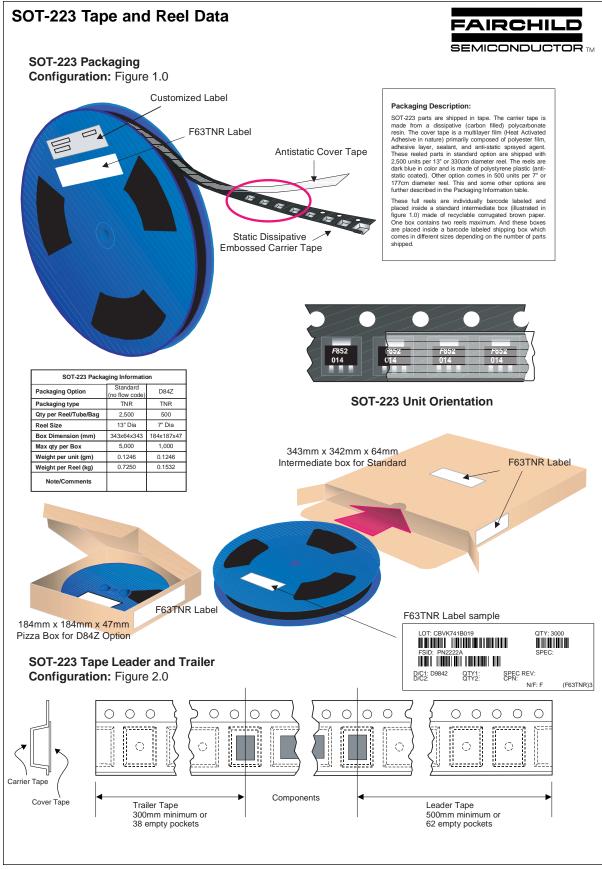


BCP54

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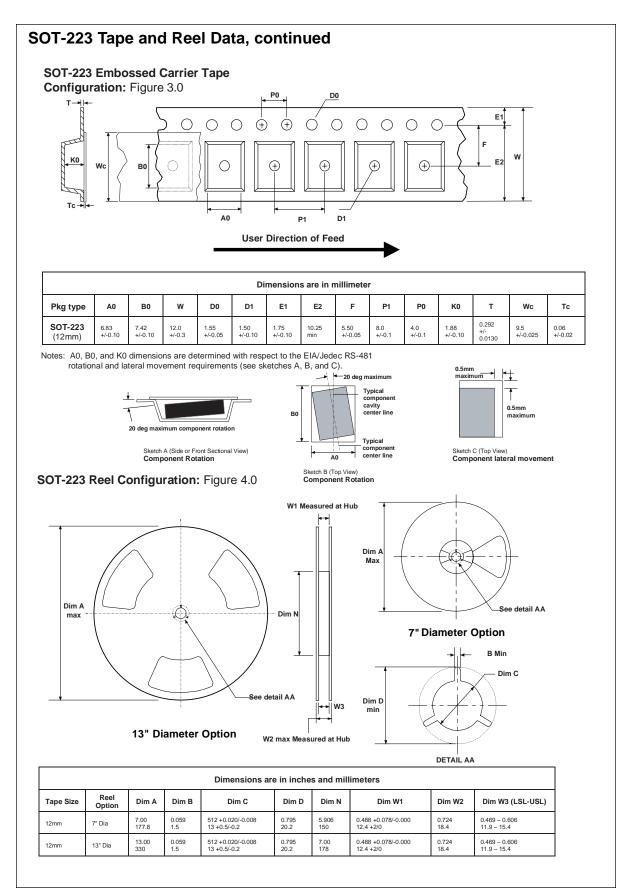
NPN General Purpose Amplifier (continued)

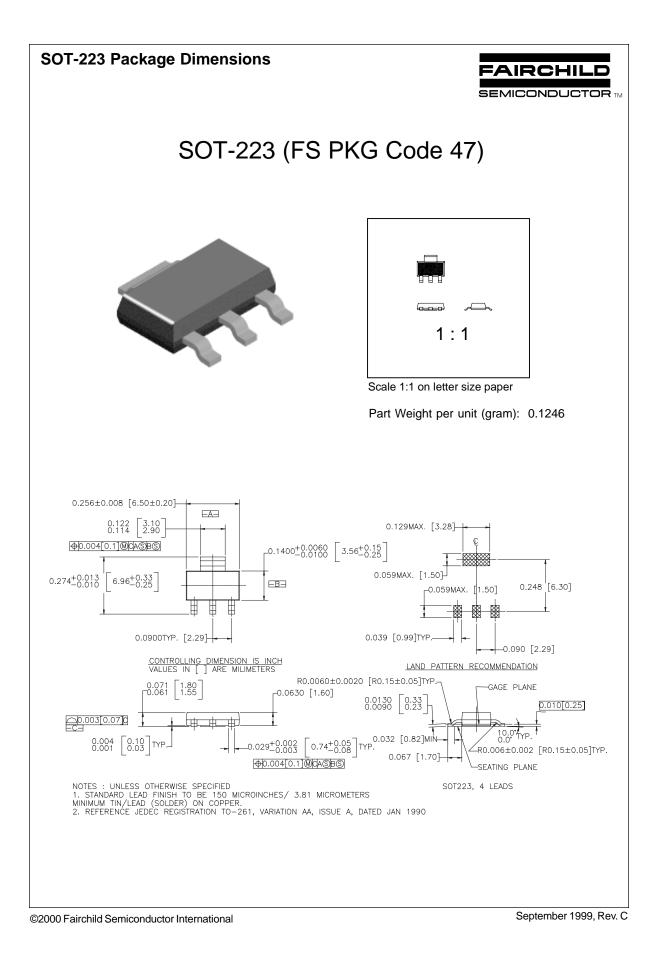




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